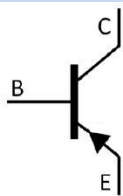


Silicon PNP transistor in a TO-126F Plastic Package.

Good linearity of h_{FE} , complementary to 2SC3422.

Audio frequency power amplifier and low speed switching applications.

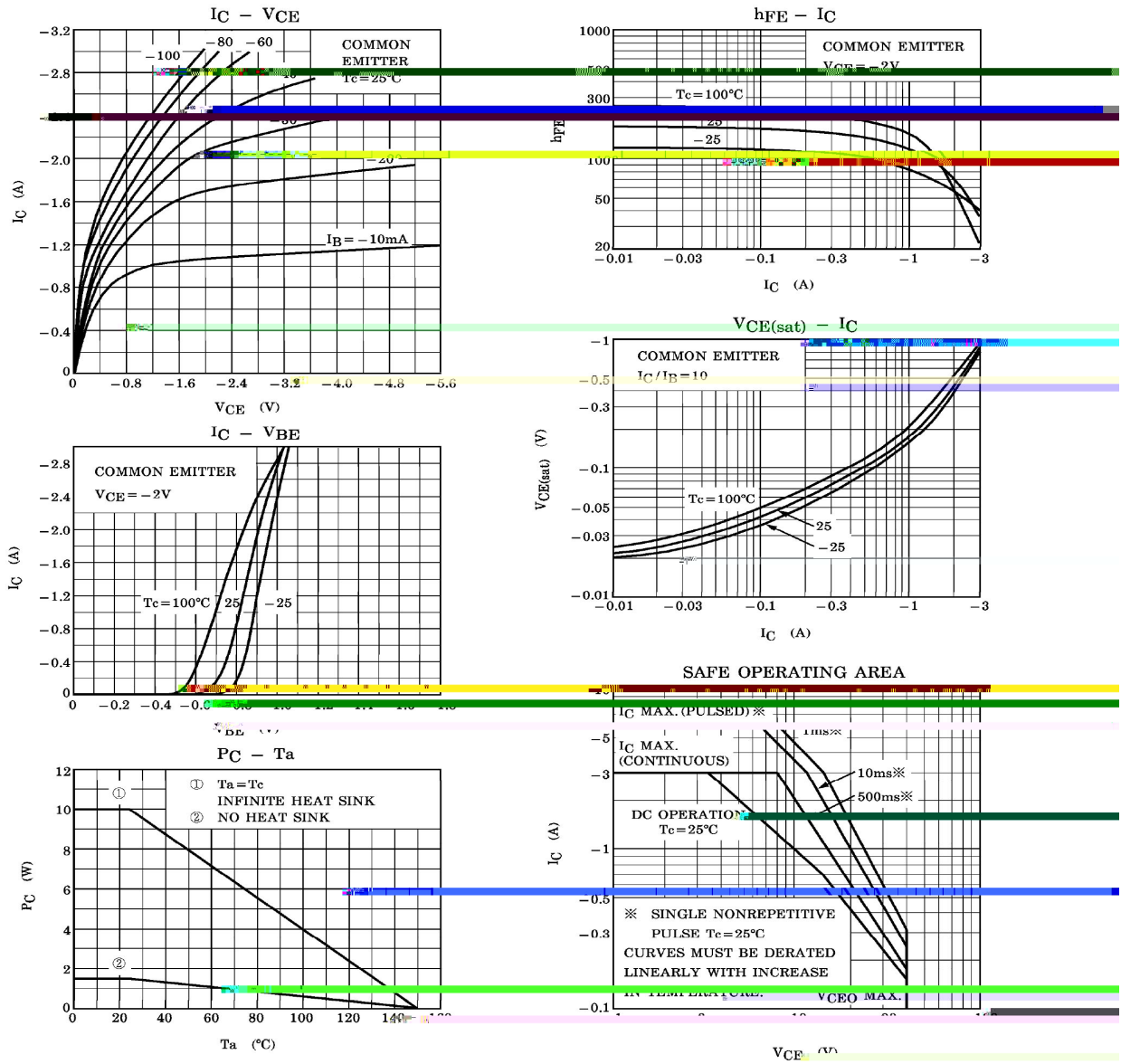


PIN1 Emitter PIN 2 Collector PIN 3 Base

h_{FE} Classifications Symbol	O	Y	GR
h_{FE} Range	80~160	120~240	200~400

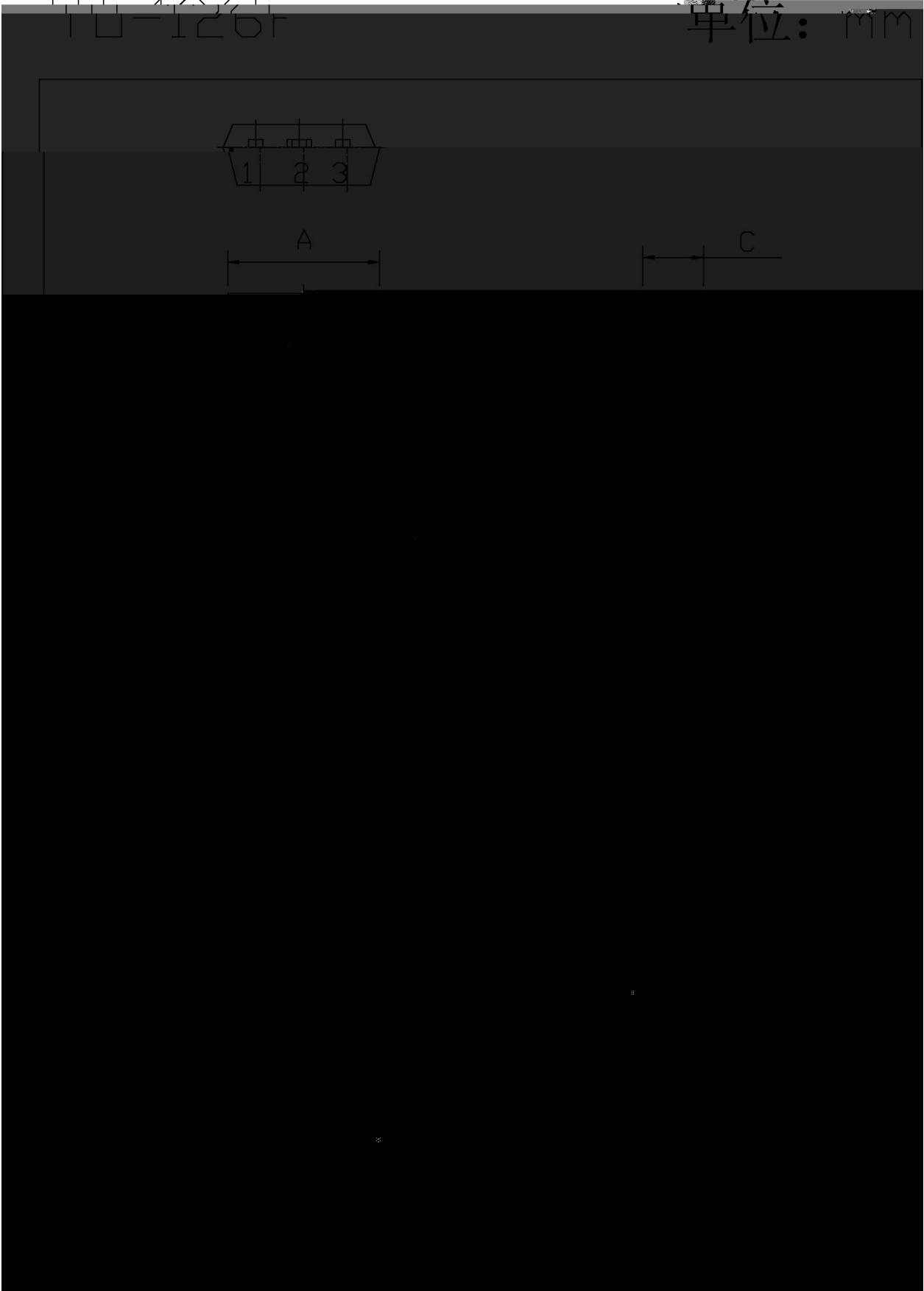
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-40	V
Collector to Emitter Voltage	V_{CEO}	-40	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-3.0	A
Base Current – Continuous	I_B	-1.0	A
Collector Power Dissipation	P_C	1.5	W
Collector Power Dissipation	$P_C(T_C=25^\circ\text{C})$	10	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55~150	

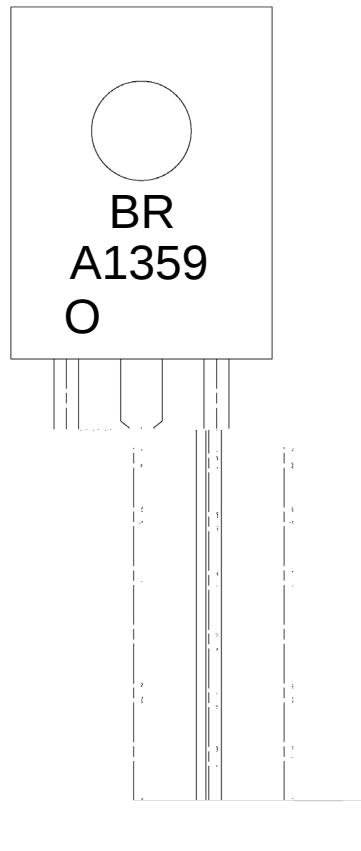
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-Off Current	I_{CBO}	$V_{CB}=-40V$ $I_E=0$			-0.1	μA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=-5.0V$ $I_C=0$			-0.1	μA
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=-10mA$ $I_B=0$	-40			V
DC Current Gain	$h_{FE(1)}$	$V_{CE}=-2.0V$ $I_C=-0.5A$	80		400	
	$h_{FE(2)}$	$V_{CE}=-2.0V$ $I_C=-2.5A$	25			
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-2.0A$ $I_B=-0.2A$			-0.8	V
Base to Emitter Voltage	V_{BE}	$V_{CE}=-2.0V$ $I_C=-0.5A$			-1.0	V
Transition Frequency	f_T	$V_{CE}=-2.0V$ $I_C=-0.5A$		100		MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=-10V$ $I_E=0$ $f=1.0MHz$		35		pF



TU-126F

单位: mm





Note:

BR: Company Code

A1359: Product Type.

O: h_{FE} Classifications Symbol

***: Lot No. Code, code change with Lot No.



- 1

25 150

60 90sec;

2

255 5

5 0.5sec;

3

2 10

/sec.
- Note:
1.Preheating:25~150 , Time:60~90sec.
2.Peak Temp.:255 5 , Duration:5 0.5sec.
3. Cooling Speed: 2~10 /sec.

270 5

10 1 sec.

Temp.:270±5

Time:10±1 sec

/ BULK

Package Type	Units 包装数量		Dimension 包装尺寸 (unit: mm ³)
封装形式	只 套管	套管 盒	只 盒